

## DM5417/DM7417 Hex Buffers with High Voltage Open-Collector Outputs

### General Description

This device contains six independent gates each of which performs a buffer function. The open-collector outputs require external pull-up resistors for proper logical operation.

### Pull-Up Resistor Equations

$$R_{MAX} = \frac{V_O (Min) - V_{OH}}{N_1 (I_{OH}) + N_2 (I_{IH})}$$

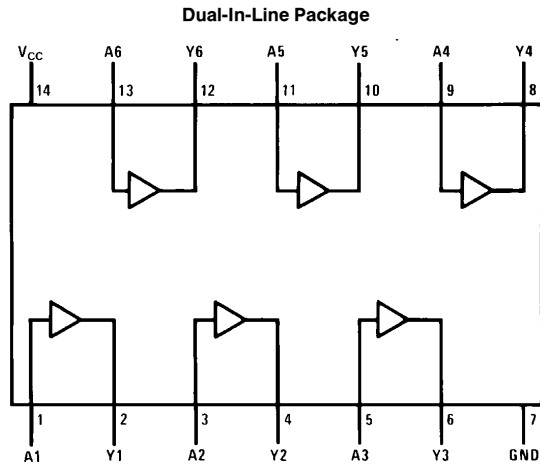
$$R_{MIN} = \frac{V_O (Max) - V_{OL}}{I_{OL} - N_3 (I_{IL})}$$

Where:  $N_1 (I_{OH})$  = total maximum output high current for all outputs tied to pull-up resistor

$N_2 (I_{IH})$  = total maximum input high current for all inputs tied to pull-up resistor

$N_3 (I_{IL})$  = total maximum input low current for all inputs tied to pull-up resistor

### Connection Diagram



TL/F/6505-1

### Function Table

Y = A

Input	Output
A	Y
L	L
H	H

H = High Logic Level  
L = Low Logic Level

## Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	7V
Input Voltage	5.5V
Output Voltage	15V
Operating Free Air Temperature Range	
DM54	–55°C to +125°C
DM74	0°C to +70°C
Storage Temperature Range	–65°C to +150°C

Note: The “Absolute Maximum Ratings” are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the “Electrical Characteristics” table are not guaranteed at the absolute maximum ratings. The “Recommended Operating Conditions” table will define the conditions for actual device operation.

## Recommended Operating Conditions

Symbol	Parameter	DM5417			DM7417			Units
		Min	Nom	Max	Min	Nom	Max	
V <sub>CC</sub>	Supply Voltage	4.5	5	5.5	4.75	5	5.25	V
V <sub>IH</sub>	High Level Input Voltage	2			2			V
V <sub>IL</sub>	Low Level Input Voltage			0.8			0.8	V
V <sub>OH</sub>	High Level Output Voltage			15			15	V
I <sub>OL</sub>	Low Level Output Current			30			40	mA
T <sub>A</sub>	Free Air Operating Temperature	–55		125	0		70	°C

## Electrical Characteristics over recommended operating free air temperature range (unless otherwise noted)

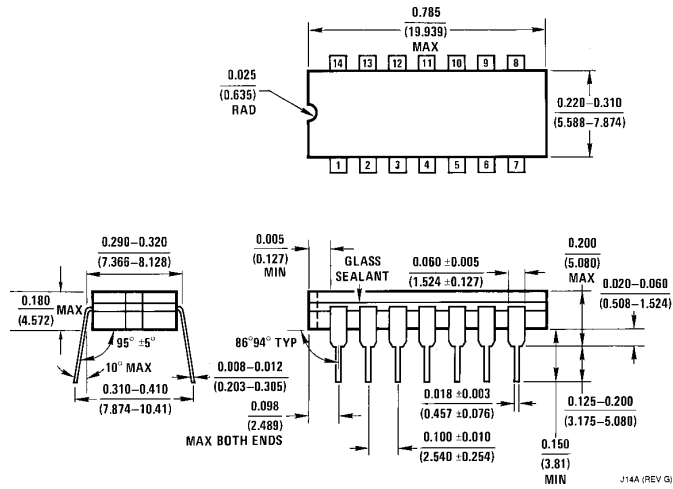
Symbol	Parameter	Conditions	Min	Typ (Note 1)	Max	Units
V <sub>I</sub>	Input Clamp Voltage	V <sub>CC</sub> = Min, I <sub>I</sub> = –12 mA			–1.5	V
I <sub>CEX</sub>	High Level Output Current	V <sub>CC</sub> = Min, V <sub>O</sub> = 15V V <sub>IH</sub> = Min			250	μA
V <sub>OL</sub>	Low Level Output Voltage	V <sub>CC</sub> = Min, I <sub>OL</sub> = Max V <sub>IL</sub> = Max			0.7	V
		I <sub>OL</sub> = 16 mA, V <sub>CC</sub> = Min			0.4	
I <sub>I</sub>	Input Current @ Max Input Voltage	V <sub>CC</sub> = Max, V <sub>I</sub> = 5.5V			1	mA
I <sub>IH</sub>	High Level Input Current	V <sub>CC</sub> = Max, V <sub>I</sub> = 2.4V			40	μA
I <sub>IL</sub>	Low Level Input Current	V <sub>CC</sub> = Max, V <sub>I</sub> = 0.4V			–1.6	mA
I <sub>CCH</sub>	Supply Current with Outputs High	V <sub>CC</sub> = Max		29	41	mA
I <sub>CCL</sub>	Supply Current with Outputs Low	V <sub>CC</sub> = Max		21	30	mA

## Switching Characteristics at V<sub>CC</sub> = 5V and T<sub>A</sub> = 25°C (See Section 1 for Test Waveforms and Output Load)

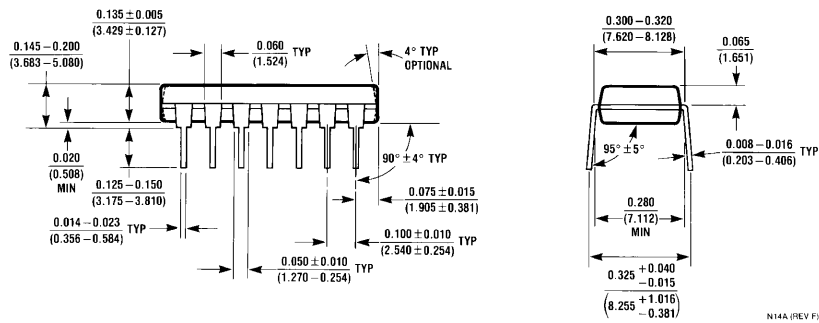
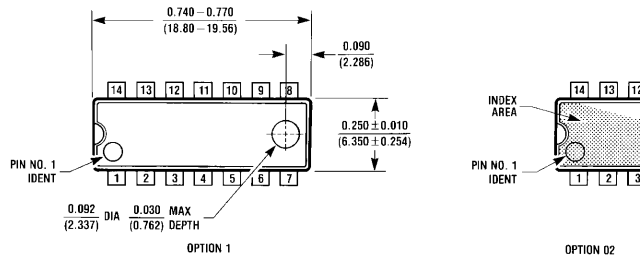
Symbol	Parameter	Conditions	Min	Max	Units
t <sub>PLH</sub>	Propagation Delay Time Low to High Level Output	C <sub>L</sub> = 15 pF R <sub>L</sub> = 110Ω		10	ns
t <sub>PHL</sub>	Propagation Delay Time High to Low Level Output			30	ns

Note 1: All typicals are at V<sub>CC</sub> = 5V, T<sub>A</sub> = 25°C.

**Physical Dimensions** inches (millimeters)



**14-Lead Ceramic Dual-In-Line Package (J)**  
**Order Number DM5417J**  
**NS Package Number J14A**



**14-Lead Molded Dual-In-Line Package (N)**  
**Order Number DM7417N**  
**NS Package Number N14A**

**Physical Dimensions** inches (millimeters) (Continued)



**14-Lead Ceramic Flat Package (W)  
Order Number DM5417W  
NS Package Number W14B**

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